## NSN 5961-00-136-4162

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View Online at https://aerobasegroup.com/nsn/5961-00-136-4162

### Inclosure Material:

Metal

## Overall Length:

Between 1.439 inches and 1.573 inches

### **Terminal Length:**

Between 0.312 inches and 0.500 inches

#### **Overall Height:**

Between 0.270 inches and 0.380 inches

#### **Overall Width:**

Between 0.990 inches and 1.050 inches

### Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

85.7 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: pnp

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 pin and 1 case

## **Specification Data:**

81349-mil-s-19500/379 government specification

## Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

